1 Description

The RedRock® RR122-3C62-511 and RR122-3C63-511 digital magnetic sensors are ideal for use in medical, industrial, automotive, and consumer applications. They are based on patented Tunneling Magnetoresistance (TMR) technology with seamless CMOS integration.

The RR122-3C62-511 and RR122-3C63-511 feature an operate sensitivity of 10 G (1.0 mT) with a bipolar magnetic field response. They offer a wide supply voltage range from 1.7V up to 5.5V, ideal for applications ranging from small battery-powered electronics to industrial machinery. They have a low average current drain (1.7 µA) for an active magnetic sensor, operating at 500 Hz and high operating temperature range from -40°C up to 125°C.

2 Features

- ▶ Operate sensitivity of 10 G
- ► Lowest Average Current < 1.7 µA
- ▶ Wide Supply Voltage Range of 1.7V 5.5V
- ▶ Bipolar Latching Push-Pull Response
- ▶ Operating Frequency of 500 Hz
- ► Temperature Rated up to 125°C
- ► RoHS & REACH Compliant

3 Applications

- ▶ Proximity Detection
- ► Linear Position Sensing
- ► Rotary Sensing
- ▶ Fluid Level Detection
- ▶ Door & Lid Closure Detection
- ► Utility Meters
- ▶ Portable Medical Devices
- ► Motor Controllers
- ► Consumer Electronics

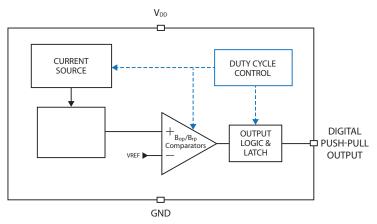
Device Information

Part Series	Package	Body Size (mm)	Temp Rating °C
RR122-3C62-511	SOT-23-3	2.9 x 1.6 x 1.2	-40 to +85
RR122-3C63-511	SOT-23-3	2.9 x 1.6 x 1.2	-40 to +125

Device Package



Functional Block Diagram for Digital Push-Pull Output



Device Nomenclature

Ordering Information

RR122-X X X X-Y Y Y Series Magnetic Polarity Response 1 = Omnipolar3 = Bipolar/Latch 2 = Unipolar Magnetic Sensitivity (G) A: Op 9, Rel 5 E: Op 15, Rel 10 B: Op 30, Rel 20 F: Op 70, Rel 50 C: Op 10, Rel -10 Clock Frequency (Hz)

1: 2 5: 250 9: 10000 2: 10 6: 500 U: 100+Turbo (10000)

Package 1: SOT-23-3 2: LGA-4 5: SOT-23-5 **Output Response** 1: Active Low Supply Voltage (V) 5: 1.7 - 5.5 Temp Rating (°C)

2: -40 - +85

3: -40 - +125

3: 20 7: 2500



4 Specifications

4.1 Absolute Environmental Ratings^{1,2}

Parameters	Units	Min	Тур	Max
Operating Temperature (T _{OP}) (RR122-3C62-511)	°C	-40		+85
Operating Temperature (T _{OP}) (RR122-3C63-511)	°C	-40		+125
Storage Temperature (T _{STG})	°C	-65		+150
Junction Temperature (T _J)	°C			+150
Soldering Temperature (3 cycles, 1 min.) (T _{SOL})	°C			+260
ESD Level Human Body Model per JESD22-A114	V	±4000		
Junction-to-Ambient Thermal Resistance	°C/W		215	
Maximum Magnetic Field Exposure (B _{MAX})	G			600

4.2 Absolute Electrical Ratings^{1,2}

Parameters	Units	Min	Тур	Max
Supply Voltage (V _{DD})	V	-0.3		6.0
Push-pull Output (Active Low)(V _{OUT_PP})	V	-0.3		V_{DD}
Input and Output Current (I _{IN} /I _{OUT})	mA			±20

Notes

 $^{2.\,}Unless\,otherwise\,specified,\,all\,characteristics\,are\,measured\,at\,25^{o}C.$



ESD Note: This product uses semiconductors that can be damaged by electrostatic discharge (ESD). When handling, proper ESD precautions should be taken to avoid performance degradation or loss of functionality. Damage due to inappropriate handling is not covered under warranty.



^{1.} Exceeding Absolute Ratings may cause permanent damage to the device. Exposure at the maximum rated conditions for extended periods of time may also affect device reliability.



4 Specifications (cont.)

4.3 Operating Electrical Characteristics for RR122-3C62-511 and RR122-3C63-5111

Parameters	Units	Min	Тур	Max
Supply Voltage (V _{DD})	V	1.7	3.0	5.5
Power-On Time $(t_{ON})(V_{DD} > 90\%)$	μs		50	75
Peak Power-On Current	mA			1.4
Output Voltage (High) (V _{OUTH})	V	90% V _{DD}		
Output Voltage (Low) (V _{OUTL})	V			$10\%V_{\text{DD}}$
Under Voltage Lockout Threshold Rising V _{DD} (V _{UVLO-RISE})	V		1.60	1.64
Under Voltage Lockout Threshold Falling V_{DD} ($V_{UVLO-FALL}$)	V	1.44	1.53	
Under Voltage Lockout Hysteresis (V _{UV-HYST})	mV		50	
Average Supply Current @ V_{DD} =1.7 V, f_{SW} =500 Hz (Idd _{AVG}) ²	μΑ		1.7	
Average Supply Current @ V_{DD} =3.0 V, f_{SW} =500 Hz (Idd _{AVG}) ²	μΑ		1.9	

Notes:

- 1. Unless otherwise specified, $V_{DD} = 1.7 \text{ V}$ to 5.5 V, $T_A = -40 ^{\circ}\text{C}$ to $+85 ^{\circ}\text{C}$ (3C62), $-40 ^{\circ}\text{C}$ to $+125 ^{\circ}\text{C}$ (3C63). Typical values are $V_{DD} = 3.0 \text{ V}$ and $T_A = +25 ^{\circ}\text{C}$.
- 2. Conditions: t = 10 seconds



ESD Note: This product uses semiconductors that can be damaged by electrostatic discharge (ESD). When handling, proper ESD precautions should be taken to avoid performance degradation or loss of functionality. Damage due to inappropriate handling is not covered under warranty.

4.4 Operating Characteristics for RR122-3C62-511 and RR122-3C63-5111

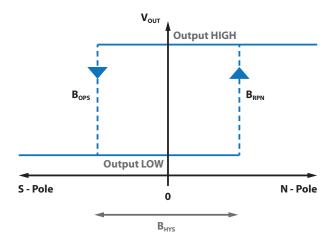
Parameters	Units	Min	Тур	Max
Switching Frequency (f _{sw})	Hz	300	500	700
Active Mode Time (t _{ACT})	μs		2.6	
Idle Mode Time @f _{sw} =500 Hz (t _{IDLE})	ms	1.4	2	3.3
Operate Point (B _{OPS})	G	-13	-10	-7
Release Point (B _{RPN})	G	7	10	13

Notes:

1. Unless otherwise specified, $V_{DD} = 1.7 \text{ V}$ to 5.5 V, $T_A = -40 ^{\circ}\text{C}$ to $+85 ^{\circ}\text{C}$ (3C62), $-40 ^{\circ}\text{C}$ to $+125 ^{\circ}\text{C}$ (3C63). Typical values are $V_{DD} = 3.0 \text{ V}$ and $T_A = +25 ^{\circ}\text{C}$.



5 Output Response vs. Magnetic Flux

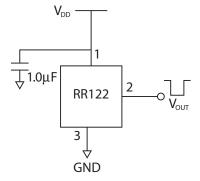


6 Application Information

RR122 Push-Pull Output Application Circuit

The output voltage on the RR122 is active low, meaning that while a sufficiently strong magnetic field is present, the output voltage is low. The output voltage can be connected to a digital I/O pin on a microcontroller. A decoupling capacitor with a minimum value of 1.0 μ F placed within 10 mm of the sensor is required.

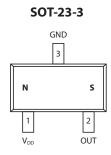
Application Circuit (SOT-23-3)



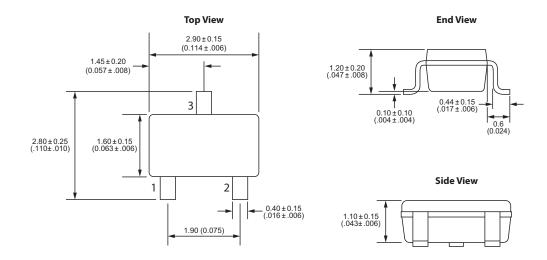




7 Axis of Sensitivity



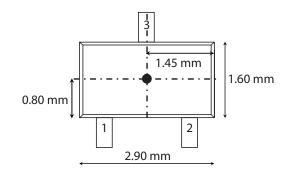
8 Dimensions SOT-23-3 Package Millimeters (Inches)



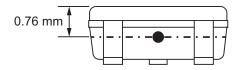


9 TMR Sensor Location

SOT-23-3 Package



SOT Package - Side View



10 Output Behavior vs. Magnetic Field Diagrams

Output Behavior vs. Magnetic Field - Bipolar

Characteristics	Conditions	Output
South Pole	B < B _{OPS}	Low (ON)
North Pole	B > B _{RPN}	High (OFF)

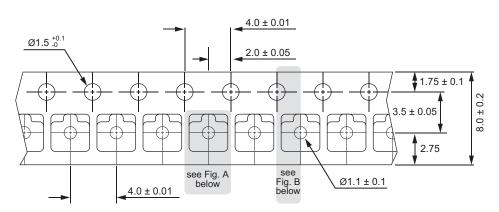




12 TMR Sensor & Switch Packaging

SOT-23-3 Tape & Reel Packaging

Standard packaging is Tape & Reel containing 3,000 pieces. MSL Rating is 1.



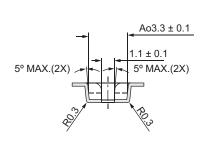
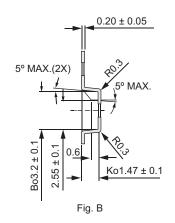
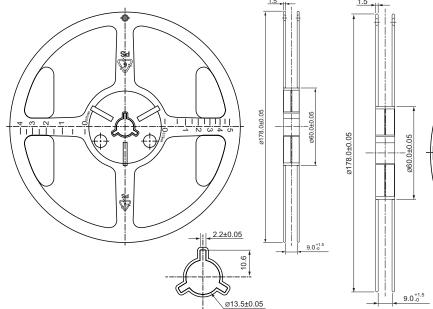
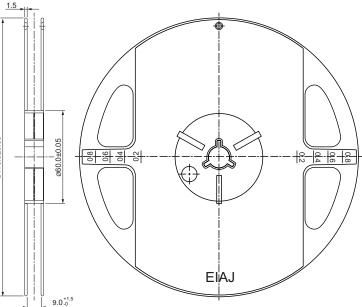


Fig. A









12 TMR Sensor & Switch Packaging

12.2 RedRock TMR Packaging

Box Dimensions - 14x10x6 inches

- Fits 1 to 3 reels = 3000 to 9000 pcs
- Weight for 3000 pcs = 0.90 kilos
- Weight for 9000 pcs = 1.00 kilos

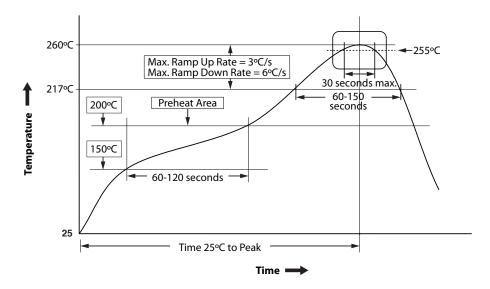
Box Dimensions - 18x14x12 inches

- Fits 4 to 24 reels = 12000 to 72000 pcs
- Weight for 12000 pcs = 1.50 kilos
- Weight for 72000 pcs = 4.90 kilos

13 Suggested Pb-Free Reflow Profile

Notes:

- 1. Fully compatible with standard no-lead solder profile, 260 °C for 30 seconds max (3 cycles max).
- 2. Profile shown as example. Users are advised to develop their own board-level profile.
- 3. Suggested Pb-free reflow profile derived from IPC/JEDEC J-STD-020E.
- 4. Temperature tolerance: +0 °C, as measured at any point on the package or leads
- 5. MSL rating of 1 (SOT-23-3 only) compatible with J-STD-020 or equivalent.
- 6. MSL rating of 3 (LGA-4 and Leaded LGA-4) compatible with J-STD-020 or equivalent.
- 7. All temperatures refer to the center of the package, measured on the package body surface that is facing up during assembly reflow (e.g., livebug). If parts are reflowed in other than the normal live bug assembly reflow orientation (i.e., dead-bug), Tp shall be within ± 2 °C of the live bug Tp and still meet the Tc requirements, otherwise, the profile shall be adjusted to achieve the latter. To accurately measure actual peak package body temperatures, refer to JEP140 for recommended thermocouple use.
- 8. Reflow profiles in this document are for classification/preconditioning and are not meant to specify board assembly profiles. Actual board assembly profiles should be developed based on specific process needs and board designs and should not exceed the parameters in this table.

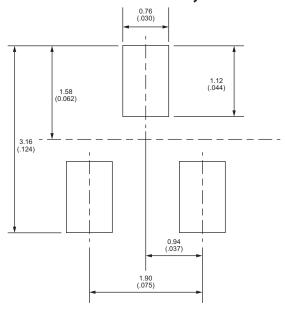






14 Suggested Solder Pad Layout

SOT-23-3 Solder Pad Layout



Revision History

	Date	Description
1	10/13/2020	Added Maximum Magnetic Field Exposure Value (Table 4.1)
2	10/13/2020	Modified Input and Output Current (Table 4.2)
3	10/13/2020	Modified UVLO Rise Value (Table 4.3)
4	10/13/2020	Modified UVLO Fall Value (Table 4.3)
5	10/13/2020	Added Supply Voltage, Typical (Table 4.3)
6	10/13/2020	Modified Switching Frequency MIN & MAX Values (Table 4.4)
7	10/13/2020	Modified Active Mode Time Value (Table 4.4)
8	10/13/2020	Added MIN & MAX Values to Idle Mode (Table 4.4)
9	10/13/2020	Modified Operate Point (BopN) MIN Value (Table 4.4)
10	10/13/2020	Modified Operate Point (BopS) MAX Value (Table 4.4)
11	10/14/2020	Modified Supply Voltage MAX Value (Table 4.2)